

# BT131 series

Triacs logic level

Rev. 08 — 9 September 2005

Product data sheet

## 1. Product profile

### 1.1 General description

Passivated, sensitive gate triacs in a SOT54 plastic package

### 1.2 Features

- Designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

### 1.3 Applications

- General purpose switching and phase control

### 1.4 Quick reference data

- $V_{DRM} \leq 600 \text{ V}$  (BT131-600)
- $V_{DRM} \leq 800 \text{ V}$  (BT131-800)
- $I_{T(RMS)} \leq 1 \text{ A}$
- $I_{TSM} \leq 12.5 \text{ A}$

## 2. Pinning information

Table 1: Pinning

Pin	Description	Simplified outline	Symbol
1	main terminal 2 (T2)	<p>SOT54 (TO-92)</p>	<p>sym051</p>
2	gate (G)		
3	main terminal 1 (T1)		

### 3. Ordering information

**Table 2: Ordering information**

Type number	Package		
	Name	Description	Version
BT131-600	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54
BT131-800			

### 4. Limiting values

**Table 3: Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage				
	BT131-600		[1] -	600	V
	BT131-800		-	800	V
$I_{\text{T(RMS)}}$	RMS on-state current	all conduction angles; $T_{\text{lead}} = 51.2\text{ °C}$ ; see <a href="#">Figure 1</a> , <a href="#">4</a> and <a href="#">5</a>	-	1	A
$I_{\text{TSM}}$	non-repetitive peak on-state current	half sine wave; $T_j = 25\text{ °C}$ prior to surge; see <a href="#">Figure 2</a> and <a href="#">3</a>			
		$t = 20\text{ ms}$	-	12.5	A
		$t = 16.7\text{ ms}$	-	13.8	A
$I^2t$	$I^2t$ for fusing	$t = 10\text{ ms}$	-	1.28	$\text{A}^2\text{s}$
$dl_{\text{T}}/dt$	rate of rise of on-state current	$I_{\text{TM}} = 1.5\text{ A}$ ; $I_{\text{G}} = 20\text{ mA}$ ; $dl_{\text{G}}/dt = 200\text{ mA}/\mu\text{s}$			
		T2+ G+	-	50	$\text{A}/\mu\text{s}$
		T2+ G-	-	50	$\text{A}/\mu\text{s}$
		T2- G-	-	50	$\text{A}/\mu\text{s}$
		T2- G+	-	10	$\text{A}/\mu\text{s}$
$I_{\text{GM}}$	peak gate current		-	2	A
$P_{\text{GM}}$	peak gate power		-	5	W
$P_{\text{G(AV)}}$	average gate power	over any 20 ms period	-	0.1	W
$T_{\text{stg}}$	storage temperature		-40	+150	$^{\circ}\text{C}$
$T_j$	junction temperature		-	125	$^{\circ}\text{C}$

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 A/ $\mu\text{s}$ .

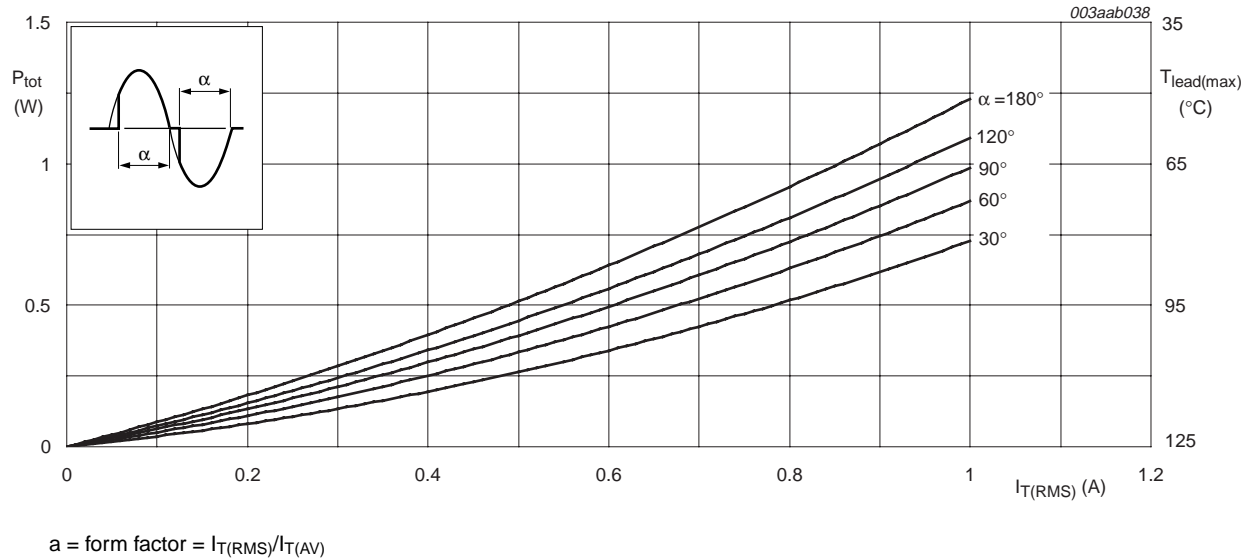


Fig 1. Total power dissipation as a function of average on-state current; maximum values

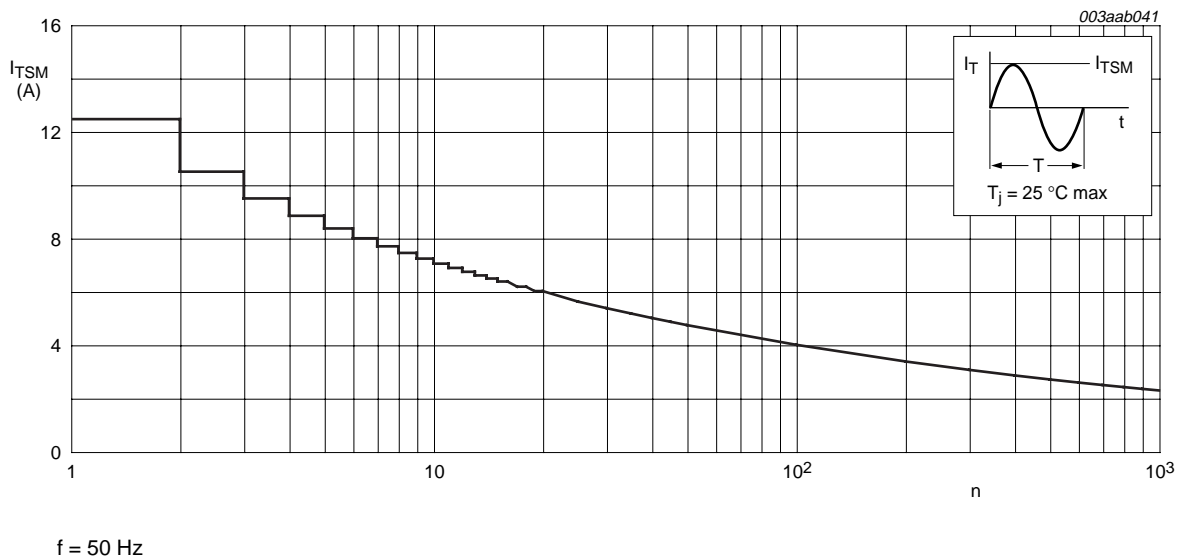
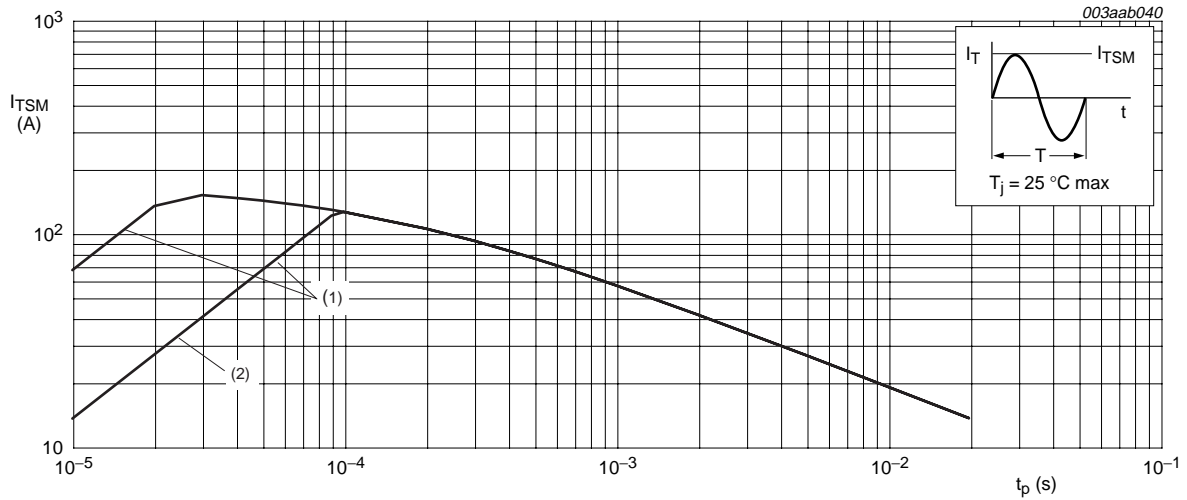


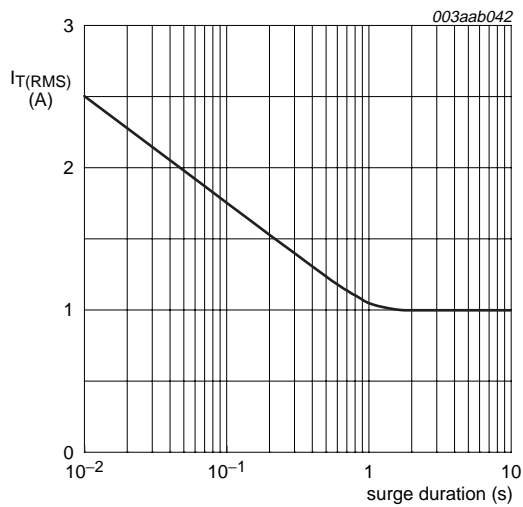
Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values



$t_p \leq 20\text{ ms}$

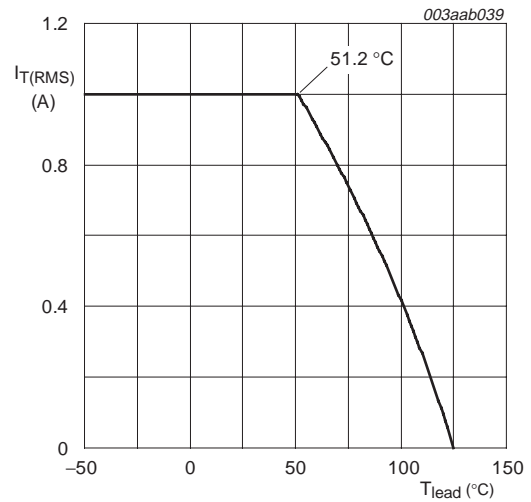
- (1)  $dI_T/dt$  limit
- (2) T2- G+ quadrant

**Fig 3. Non-repetitive peak on-state current as a function of pulse width for sinusoidal currents; maximum values**



$f = 50\text{ Hz}; T_{lead} \leq 51.2\text{ °C}$

**Fig 4. RMS on-state current as a function of surge duration, for sinusoidal currents; maximum values**



(1)  $T_{lead} = 51.2\text{ °C}$

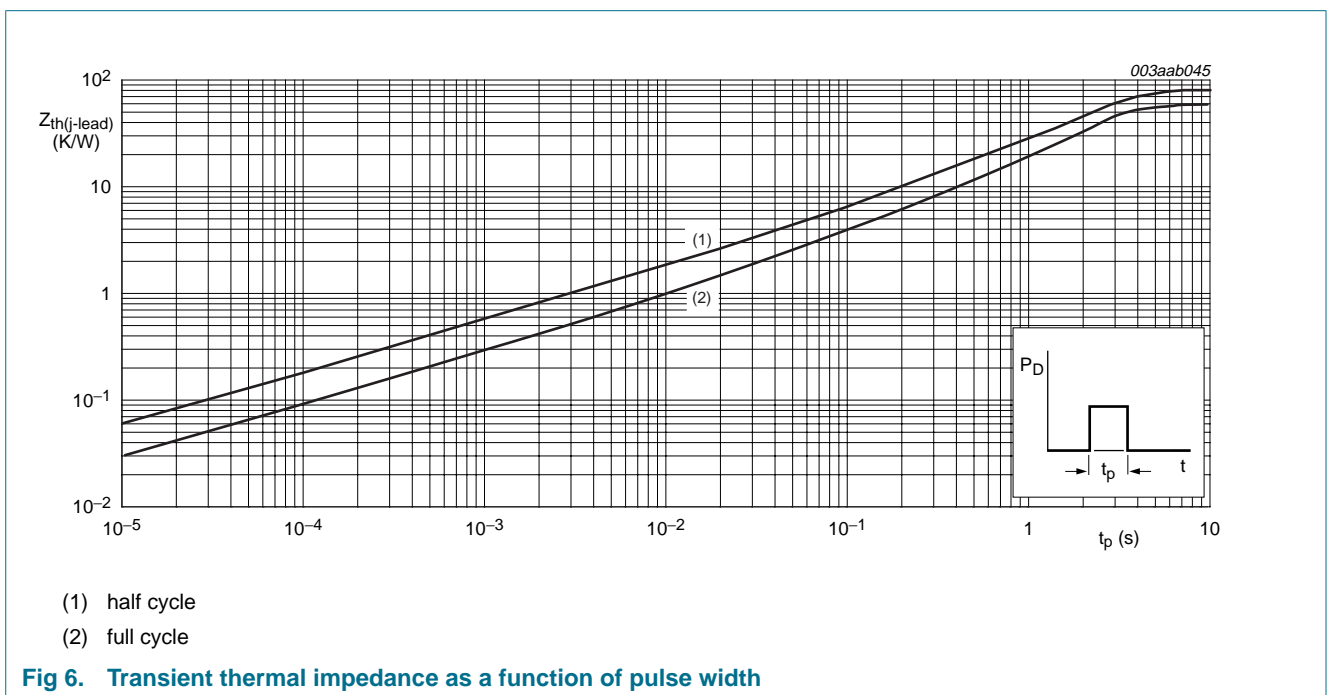
**Fig 5. RMS on-state current as a function of lead temperature; maximum values**

## 5. Thermal characteristics

**Table 4: Thermal characteristics**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle	-	-	60	K/W
		half cycle	-	-	80	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	see <a href="#">Figure 6</a>	[1] -	150	-	K/W

[1] Mounted on a printed-circuit board; lead length = 4 mm



## 6. Characteristics

**Table 5: Characteristics**

$T_j = 25\text{ °C}$  unless otherwise stated.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 100\text{ mA}$ ; see <a href="#">Figure 8</a>				
		T2+ G+	-	0.4	3	mA
		T2+ G-	-	1.3	3	mA
		T2- G-	-	1.4	3	mA
		T2- G+	-	3.8	7	mA
$I_L$	latching current	$V_D = 12\text{ V}$ ; $I_{GT} = 100\text{ mA}$ ; see <a href="#">Figure 10</a>				
		T2+ G+	-	1.2	5	mA
		T2+ G-	-	4	8	mA
		T2- G-	-	1	5	mA
		T2- G+	-	2.5	8	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $I_{GT} = 100\text{ mA}$ ; see <a href="#">Figure 11</a>	-	1.3	5	mA
$V_T$	on-state voltage	$I_T = 1.4\text{ A}$ ; see <a href="#">Figure 9</a>	-	1.2	1.5	V
$V_{GT}$	gate trigger voltage	$I_T = 10\text{ mA}$ ; gate open circuit; see <a href="#">Figure 7</a>				
		$V_D = 12\text{ V}$ ; $I_{GT} = 100\text{ mA}$	-	0.7	1.5	V
		$V_D = 400\text{ V}$ ; $I_{GT} = 100\text{ mA}$ ; $T_j = 125\text{ °C}$	0.2	0.3	-	V
$I_D$	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125\text{ °C}$	-	0.1	0.5	mA
<b>Dynamic characteristics</b>						
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}$ ; $T_j = 125\text{ °C}$ ; exponential waveform; $R_{GK} = 1\text{ k}\Omega$ ; see <a href="#">Figure 12</a>	10	20	-	V/ $\mu$ s
$dV_{com}/dt$	rate of change of commutating current	$V_{DM} = 400\text{ V}$ ; $T_j = 125\text{ °C}$ ; $dl_{com}/dt = 0.5\text{ A/ms}$	2	-	-	V/ $\mu$ s
$t_{gt}$	gate-controlled turn-on time	$I_{TM} = 1.5\text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 100\text{ mA}$ ; $dl_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	$\mu$ s

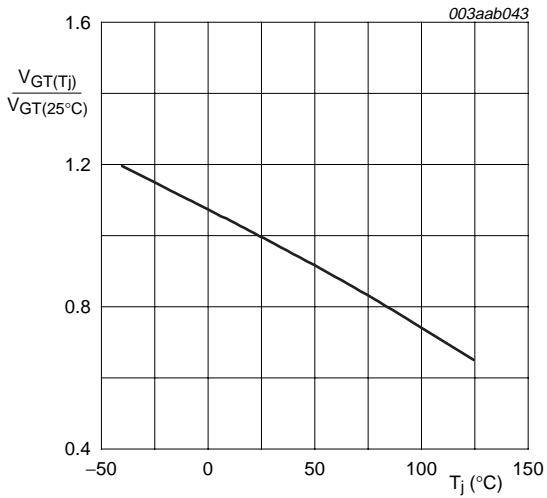
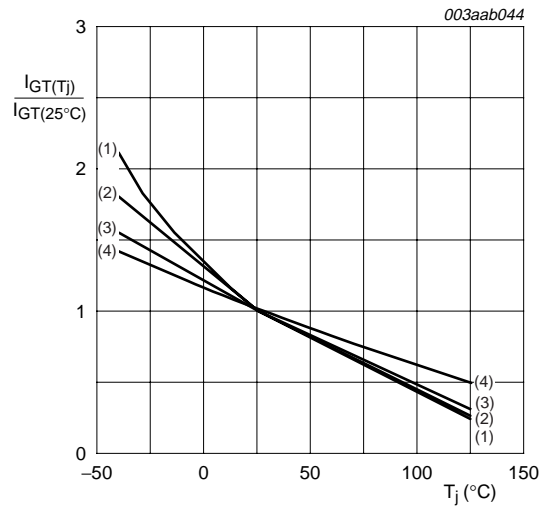
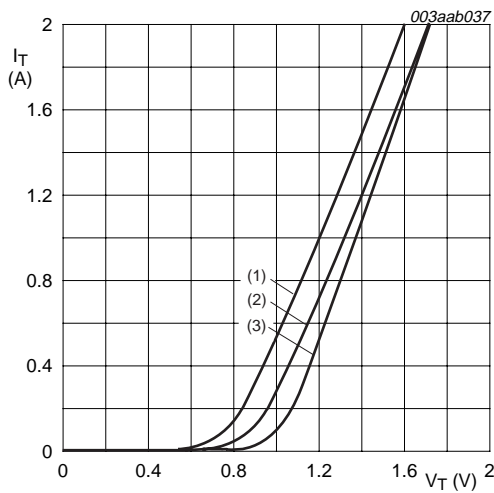


Fig 7. Normalized gate trigger voltage as a function of junction temperature



- (1) T2- G+
- (2) T2- G-
- (3) T2+ G-
- (4) T2+ G+

Fig 8. Normalized gate trigger current as a function of junction temperature



$V_o = 0.92 \text{ V}$   
 $R_s = 0.4 \text{ } \Omega$ .

- (1)  $T_j = 125 \text{ }^\circ\text{C}$ ; typical values
- (2)  $T_j = 125 \text{ }^\circ\text{C}$ ; maximum values
- (3)  $T_j = 25 \text{ }^\circ\text{C}$ ; maximum values

Fig 9. On-state current characteristics

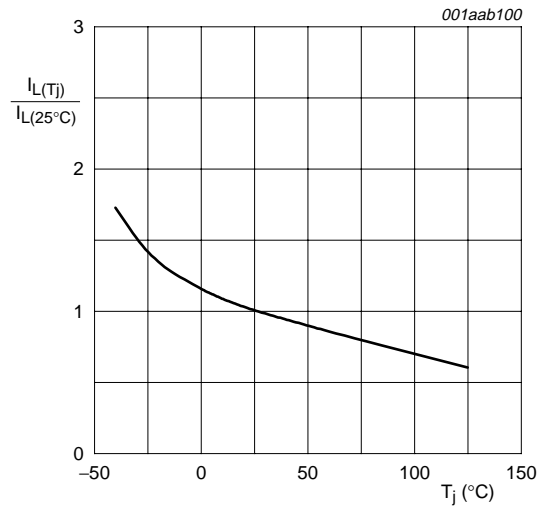
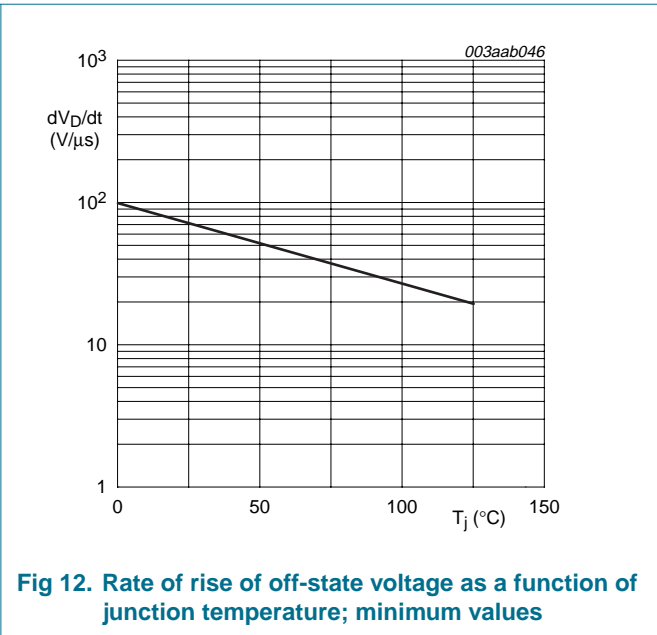
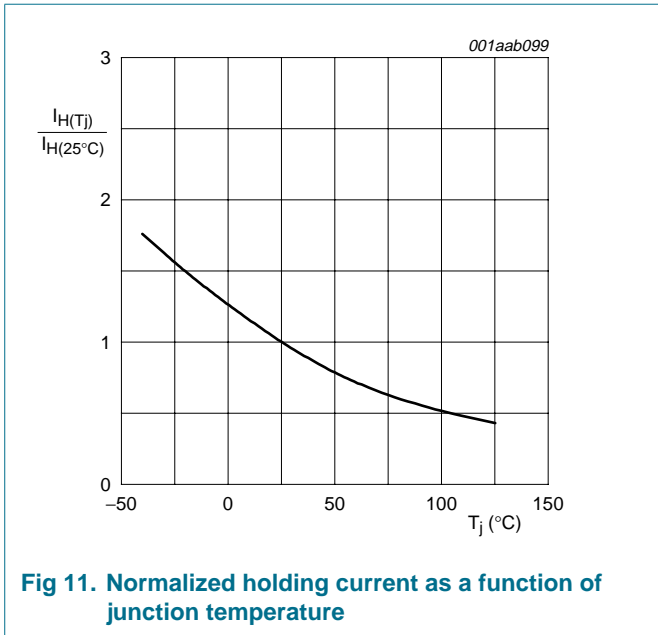


Fig 10. Normalized latching current as a function of junction temperature



## 7. Package information

Epoxy meets requirements of UL94 V-0 at 1/8 inch.



8. Package outline

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

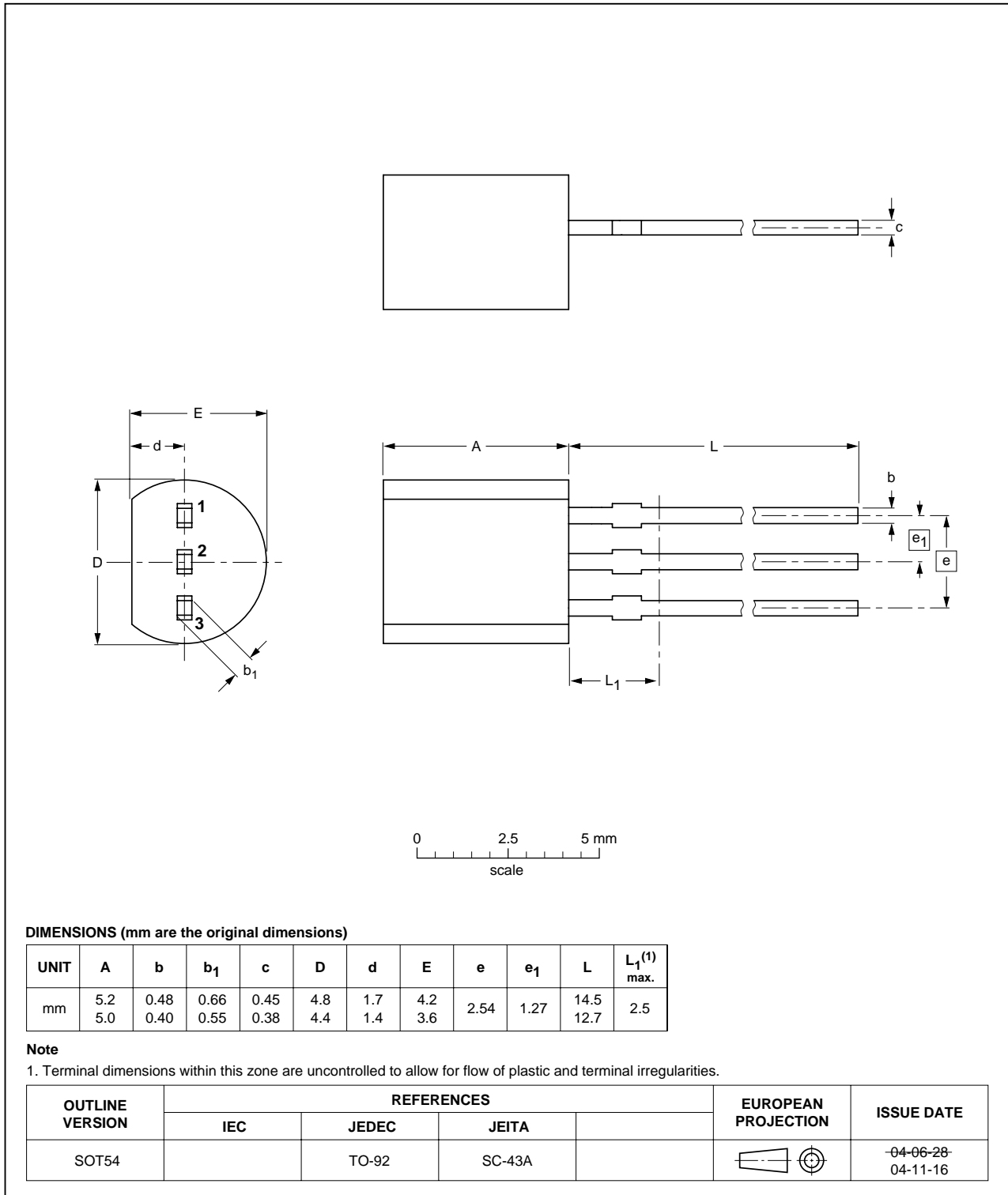


Fig 13. Package outline SOT54 (TO-92)

## 9. Revision history

**Table 6: Revision history**

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BT131_SER_8	20050909	Product data sheet	-	-	BT131_SER_7
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new presentation and information standard of Philips Semiconductors.</li><li>• <a href="#">Figure 5</a>: corrected</li></ul>				
BT131_SER_7	20040101	Product specification	-	-	BT131_SER_6
BT131_SER_6	20030801	Product specification	-	-	BT131_SER_5
BT131_SER_5	20001201	Product specification	-	-	BT131_SER_4
BT131_SER_4	20000501	Product specification	-	-	BT131_SER_3
BT131_SER_3	19980401	Product specification	-	-	-

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Level	Data sheet status <sup>[1]</sup>	Product status <sup>[2] [3]</sup>	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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## 15. Contents

<b>1</b>	<b>Product profile</b> . . . . .	<b>1</b>
1.1	General description . . . . .	1
1.2	Features . . . . .	1
1.3	Applications . . . . .	1
1.4	Quick reference data . . . . .	1
<b>2</b>	<b>Pinning information</b> . . . . .	<b>1</b>
<b>3</b>	<b>Ordering information</b> . . . . .	<b>2</b>
<b>4</b>	<b>Limiting values</b> . . . . .	<b>2</b>
<b>5</b>	<b>Thermal characteristics</b> . . . . .	<b>5</b>
<b>6</b>	<b>Characteristics</b> . . . . .	<b>6</b>
<b>7</b>	<b>Package information</b> . . . . .	<b>8</b>
<b>8</b>	<b>Package outline</b> . . . . .	<b>9</b>
<b>9</b>	<b>Revision history</b> . . . . .	<b>10</b>
<b>10</b>	<b>Data sheet status</b> . . . . .	<b>11</b>
<b>11</b>	<b>Definitions</b> . . . . .	<b>11</b>
<b>12</b>	<b>Disclaimers</b> . . . . .	<b>11</b>
<b>13</b>	<b>Trademarks</b> . . . . .	<b>11</b>
<b>14</b>	<b>Contact information</b> . . . . .	<b>11</b>



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